

LIMITER/AMPLIFIER

The TBA750C is a limiter/amplifier with f.m. detector, d.c. volume control and a.f. preamplifier. It is intended for 4,5 MHz, 5,5 MHz or 10,7 MHz. The limiter/amplifier is a four-stage differential amplifier that gives very good noise and interference suppression. The detector is of the balanced type. The d.c. volume control stage has excellent control characteristics with a control range of more than 80 dB. The a.f. preamplifier can drive a triode-pentode output stage or a class-A push-pull transistor output stage.

QUICK REFERENCE DATA

Supply voltage	V_{2-5}	typ	12 V
Total current drain	I_{tot}	typ	34 mA
Frequency	f_0		5,5 MHz
Input voltage at start of limiting	$V_{i\ lim}$	typ	130 μ V
A.M. rejection at $V_i = 1$ mV	α	typ	45 dB
A.F. output voltage at $\Delta f = \pm 15$ kHz at pin 16	$V_o(rms)$	typ	2,7 V
D.C. volume control range	>		80 dB

PACKAGES OUTLINES

TBA750C: 16-lead DIL; plastic (SOT-38).
TBA750CQ: 16-lead QIL; plastic (SOT-58).

CIRCUIT DIAGRAM

October 1977

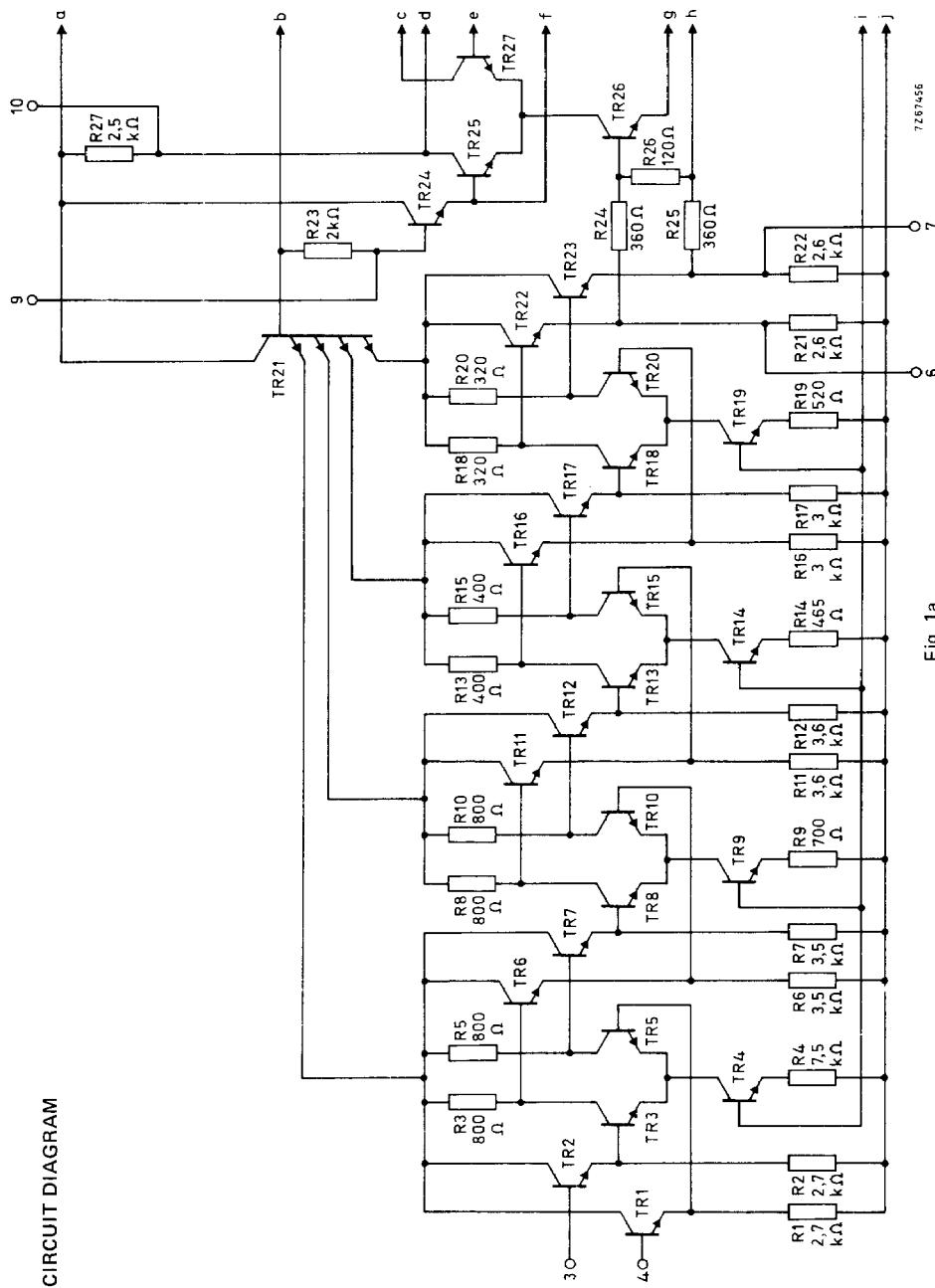


Fig. 1a.

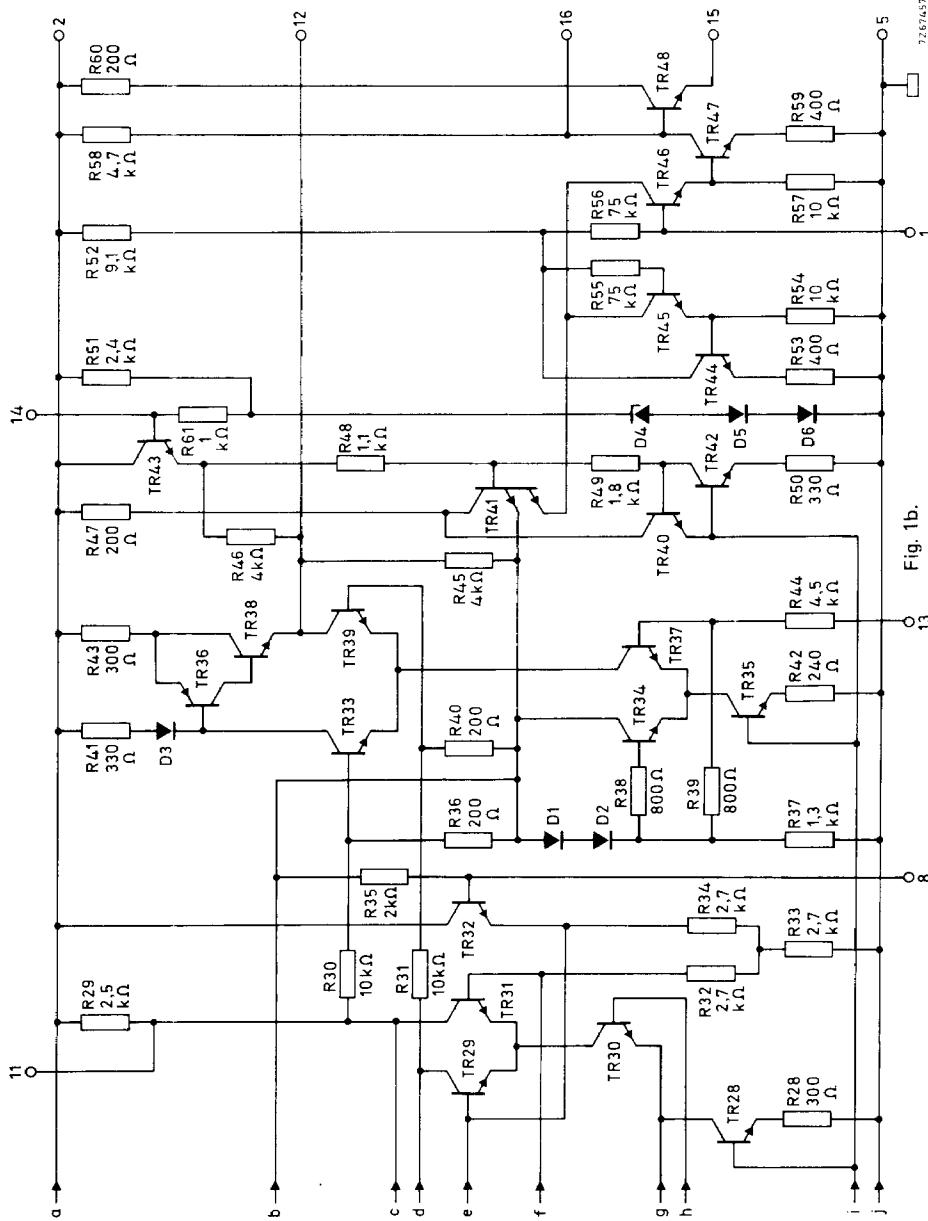


Fig. 1b.

TBA750C

TBA750CQ

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Supply voltage	V_{2-5}	max	16 V *
Storage temperature	T_{stg}	-55 to + 125	°C
Operating ambient temperature	T_{amb}	-25 to + 55	°C
Power dissipation			

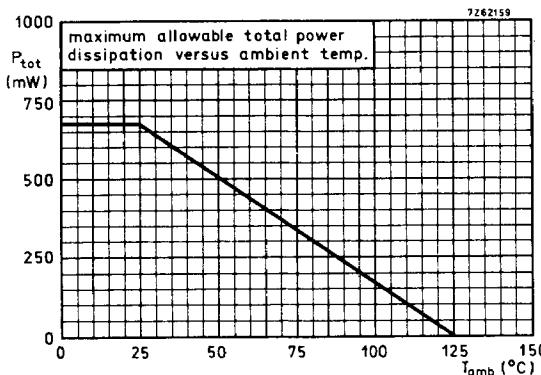


Fig. 2.

CHARACTERISTICS

Measured in test circuit Fig. 3.

Supply voltage range

see also Fig. 4

V_{2-5} 10 to 25 V

Total current drain; pin 15 not connected

I_2 25 to 45 mA

Input limiting voltage at $V_o = -3$ dB (r.m.s. value)

$V_{i\ lim(rms)}$ typ 130 μ V

I.F. output voltage at pins 6 and 7
(peak-to-peak value)

$V_{6-5(p-p)}$	typ	380 mV
$V_{7-5(p-p)}$	typ	

A.M. rejection

$V_i = 1$ mV

α typ 45 dB

$V_i = 10$ mV

α typ 50 dB

$V_i = 100$ mV

α typ 55 dB

D.C. volume control range; see also Fig. 5

> 80 dB

A.F. preamplifier voltage gain

pin 1 to pin 16

G_V typ 10

Input resistance at pin 1

R_i \geq 35 k Ω

* Allowable only if the dissipation in the IC is limited by means of a series resistor in the supply (see also Fig. 4).

CHARACTERISTICS (continued)

A.F. output voltages (r.m.s. values)

 $\Delta f = \pm 15 \text{ kHz}$; $f_m = 1 \text{ kHz}$

$V_{10-5}(\text{rms})$	typ	65 mV
$V_{11-5}(\text{rms})$	typ	250 mV
$V_{12-5}(\text{rms})$	typ	2,7 V

Total harmonic distortion

at pin 12; $\Delta f = 15 \text{ kHz}$

d_{tot}	typ	3 %
d_{tot}	typ	2,6 %

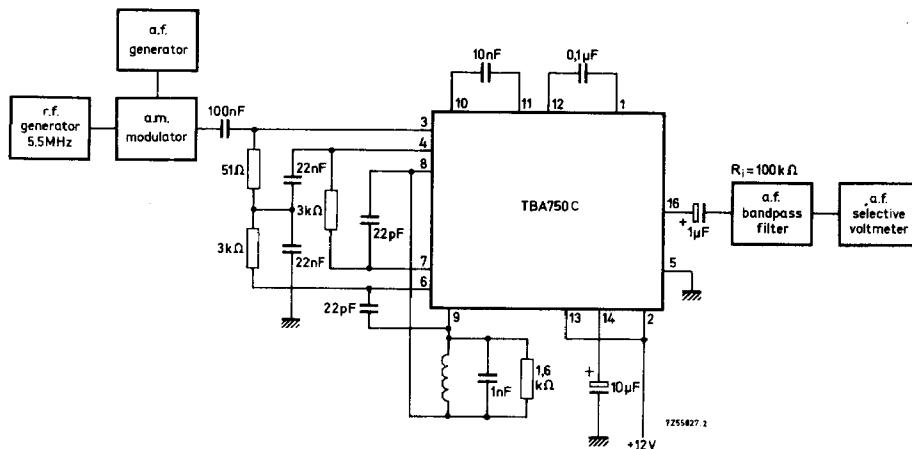
at pin 1 with respect to pin 16; $V_o(\text{rms}) = 3 \text{ V}$ 

Fig.3 Test circuit; for f.m.: $f_o = 5,5 \text{ MHz}$; $\Delta f = \pm 15 \text{ kHz}$; $f_m = 70 \text{ Hz}$.
For a.m.: $m = 0,3$; $f_m = 1 \text{ kHz}$.

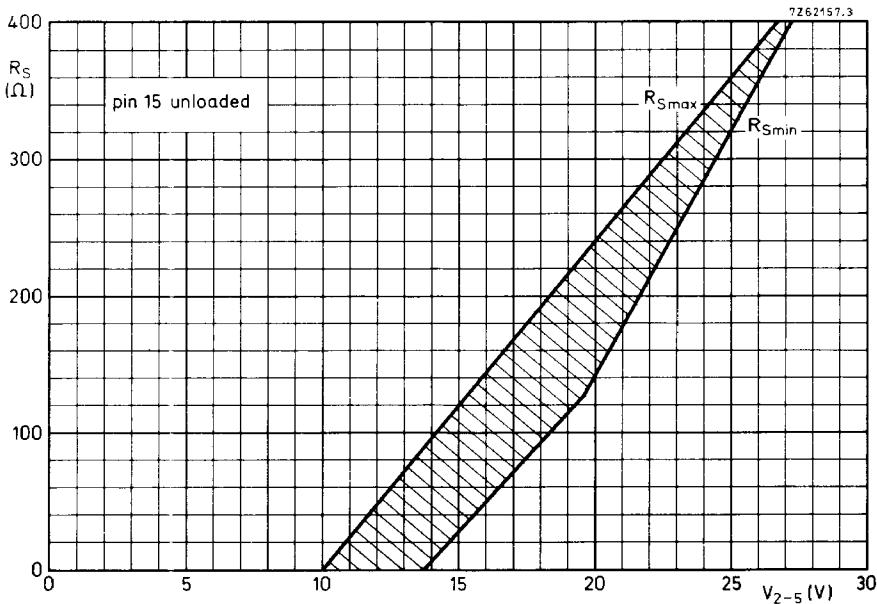


Fig. 4 Maximum and minimum values for the power supply series resistance (R_S).

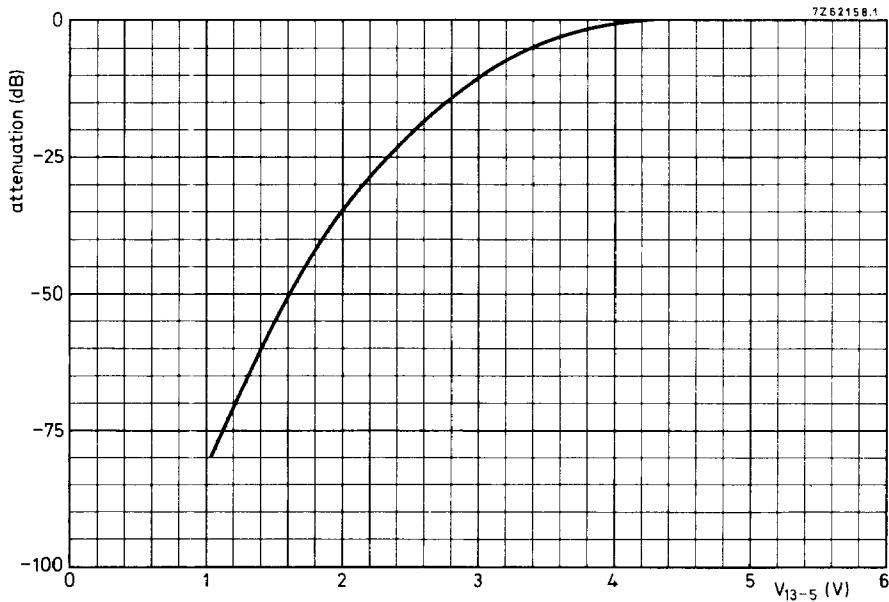


Fig. 5 Remote control characteristic.

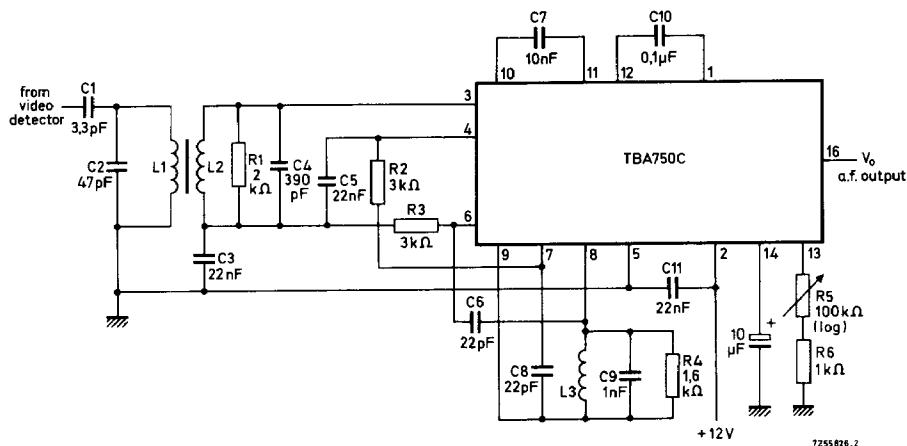
APPLICATION INFORMATION at $f = 5,5$ MHz

Fig. 6.

$$L_1 = 18 \mu\text{H}; Q_{L1} = 36$$

$$L_2 = 2,2 \mu\text{H}; Q_{L2} = 21$$

$$L_3 = 0,84 \mu\text{H}; Q_{L3} = 22$$

Note

Q_{L1} , Q_{L2} and Q_{L3} are the loaded Q-factors.

The transfer ratio of the input bandpass filter: $\frac{V_2}{V_1} = 0,54$.

The peak-to-peak bandwidth of the detector S-curve is 300 kHz.